

# RER1715 for PCN10333, PCN10544, PCN10595 & PCN10703 TSMC Taiwan Fab14 additional source for STM32 products in M10/90nm technology

## Reliability Evaluation Plan

March 23<sup>rd</sup>, 2018

MMS MCD Quality & Reliability Department



# RER1715 TSMC Fab14 for STM32 products in M10/90nm technology

## STM32 Die Test Vehicles

Die Vehicle	Process Perimeter	Assembly Line	Package	Number of Reliability Lots
413	M10	ATP3	UFBGA10*10 176b	3 lots to qualify Process Perimeter Then 1 lot by Die
411		ATP3	UFBGA10*10 176b	
419		ATP3	TFBGA13*13 216b	
449		ATP3	TFBGA13*13 216b	
458	M10 ULP	JSCC	LQFP10*10 64L	3 lots to qualify Process Perimeter Then 1 lot by Die
423		ATP1	LQFP14*14 100L	
431		ATP1	LQFP14*14 100L	
441		ATP3	UFBGA10*10 144b	
433		ATP1	LQFP14*14 100L	
421		ATP1	UFBGA7*7 144b	
452		ATP3	UFBGA10*10 176b	
463		ATP3	UFBGA10*10 144b	
434		ATP3	TFBGA13*13 216b	
451		ATP3	TFBGA13*13 216b	

# RER1715 TSMC Fab14 for STM32 products in M10/90nm technology

## STM32 Die Reliability Trials

Reliability Trial & Standard		Test Conditions	Pass Criteria	Lot Strategy	Units per Lot
ESD HBM	0060102 JESD22-A114ANSI/ESDA JEDEC JS-001	25°C	2kV (class 2)	1 to 3 lots	3
ESD CDM	ESD Charged Device Model ANSI/ESD STM5.3.1	Aligned with device datasheet	250V to 500V	1 lot	3
LU	0018695 JESD78	125°C REG-ON Configuration 125°C REG-OFF Configuration	No concern	1 to 3 lots	3 3
EDR + Bake	JESD22-A117 JESD22-A103	125°C & 3.6V Cycling 150°C Bake	10k cycles 1500h 1000h	1 to 3 lots 1 <sup>st</sup> lot 2 <sup>nd</sup> & 3 <sup>rd</sup> if any	77
EDR + Bake	JESD22-A117 JESD22-A103	25°C & 3.6V Cycling 150°C Bake	10k cycles 168h	1 to 3 lots	77
EDR + Bake	JESD22-A117 JESD22-A103	-40°C & 3.6V Cycling 150°C Bake	10k cycles 168h	1 to 3 lots	77
ELFR	MIL-STD-883 Method 1005 JESD22-A108 JESD74	125°C & 3.6V	48h	3 lots by process perimeter	500 units min per lot Total of 2000 units
HTOL	MIL-STD-883 Method 1005 JESD22-A108	125°C & 3.6V 100MHz	1200h 600h	1 <sup>st</sup> lot 2 <sup>nd</sup> & 3 <sup>rd</sup> if any	77

# RER1715 TSMC Fab14 for STM32 products in M10/90nm technology

## STM32 Package Test Vehicles

Package Line	Assembly Line	Package	Wire	Die Vehicle / Rawline (*)	Number of Reliability Lots
LQFP	ATP1	LQFP10*10 64L	Au	413 / 5W*413	3 lots to qualify M10 Technology Then 1 lot by Package Assembly Line
	JSCC	LQFP10*10 64L	Ag	413 / 5W*413	
	ATP1	LQFP14*14 100L	Au	431 / 1L*431	
	ATP1	LQFP20*20 144L	Au	413 / 1A*413	
	ASE	LQFP24*24 176L	Au	413 / 1T*413	
	ATP1	LQFP28*28 208L	Au	419 / UH*419	
QFN	JSCC	UQFN7*7 48L	Ag	458 / MI*458	
UFBGA	ATP3	UFBGA10*10 176b	Au	413 / MR*413	
TFBGA	ATP3	TFBGA8*8 100b	Au	449 / DY*449	
	ATP3	TFBGA13*13 216b	Au	419 / RM*419	
WLCSP	ATT1	WLCSP 36b	NA	458 / 8Q*458	
	ATT1	WLCSP 90b	NA	413 / RI*413	
	ATT1	WLCSP 143b	NA	419 / VH*419	
	ATT1	WLCSP 180b	NA	451 / 8Z*451	

# RER1715 TSMC Fab14 for STM32 products in M10/90nm technology

## STM32 Package Reliability Trials

Reliability Trial & Standard		Test Conditions	Pass Criteria	Lot Strategy	Units per Lot
PC	Pre Conditioning: Moisture Sensitivity Jedec Level 3 J-STD-020/ JESD22-A113	Bake (125°C / 24h) Soak (30°C / 60% RH / 192h) for level 3 Convection reflow: 3 passes with Jedec level 3	3 Passes MSL3	1 to 3 lots	231 to 308 (**)
UHASt (*) (**)	Unbiased Highly Accelerated Temperature & Humidity Stress JESD22-A118	130°C, 85%RH, 2 Atm	96h	1 to 3 lots	77
TC (*)	Thermal Cycling JESD22-A104	-65°C +150°C	500Cy	1 to 3 lots	77
THB (*)	Temperature Humidity Bias JESD22-A101	85°C, 85% RH, bias	1000h	1 to 3 lots	77
HTSL (*)	High Temperature Storage Life JESD22-A103	150°C - no bias	1000h	1 to 3 lots	77
Construction Analysis	JESD22-B102	Including Solderability & Physical Dimensions	No concern	1 by package assembly line	15
	JESD22-B100/B108				10
ESD CDM	ESD Charged Device Model ANSI/ESD STM5.3.1	Aligned with device datasheet	250V to 500V	1 by package assembly line	3

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a trademark of STMicroelectronics International NV and/or its affiliates, registered in the U.S. and other countries

© 2017 STMicroelectronics International NV and/or its affiliates - All Rights Reserved

**[www.st.com](http://www.st.com)**





---

**PRODUCT/PROCESS  
CHANGE NOTIFICATION  
PCN 10703 – Additional information**

---

**TSMC (Taiwan) additional source  
for STM32F745/6 & STM32F756 products  
in M10/90nm technology**

---

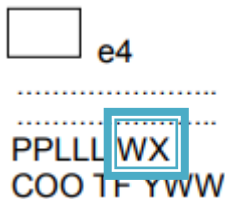
**MDG - Microcontrollers Division (MCD)**

Fab 14 TSMC is a fab already diffusing 90nm used for STM32L4 products.

Design database remains the same, except few changes on dummy structures at mask level to adapt to fab equipment.

**How can the change be seen?**

The standard marking is:



**WX** code indicates the diffusion traceability plant code.

Please refer to the DataSheet for marking details.

The marking is changing as follows:

Existing		Additional	
WX code	Fab	WX code	Fab
VQ	ST Crolles CRL300 (France)	9R	TSMC Fab14 (Taiwan)



## MCU DIVISION NOTE – October 30<sup>th</sup>, 2017

---

### M10/90nm Additional Front-end Source

---

#### MMS - Microcontrollers Division (MCD)

Dear Customer,

We are in the process to transfer ST M10/90nm eNVM technology, currently used to produce our STM32F2x, STM32F4x and STM32F7x product to TSMC Fab 14 located in Taiwan. Fab14 is currently producing STM32L4x products.

Most of the STM32F2x, STM32F4x and STM32F7x volume production will be transferred to TSMC Fab 14.

This letter is a pre-announcement. Formal PCN will follow in coming weeks.

#### Why to add a source for M10 technology

- STM32F2x, STM32F4x and STM32F7x are experimenting a big success in the market and we are facing a growing and solid demand since months.
- Our two production sites ST Rousset R8 and ST Crolles CR300 fabs will not be able to absorb all future demand. Adding TSMC Fab14 as manufacturing source will provide the flexibility to cope with future demand and further growth.

#### Products involved

- STM32F2x
- STM32F4x
- STM32F7x

#### Timing:

- We intend to complete qualification of all part number by Q3 2018.
- First PCN announcing the first part number batch of transfer will be published mid-November 2017 for delivery starting in March 2018.
- ST will do its best to support customers during the short transition time.

Sincere regards.

Veronique Barlatier  
WW Commercial Marketing Manager  
ST Microcontroller Division